

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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Nch 500V 16A Power MOSFET

V_{DSS}	500V
R _{DS(on)} (Max.)	0.325Ω
I _D	±16A
P _D	255W

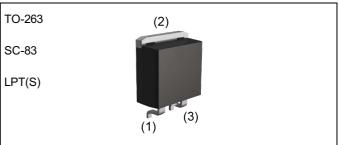
● Features

- 1) Fast reverse recovery time (trr).
- 2) Low on-resistance.
- 3) Fast switching speed.
- 4) Gate-source voltage (V_{GSS}) guaranteed to be $\pm 30V$.
- 5) Drive circuits can be simple.
- 6) Pb-free lead plating; RoHS compliant

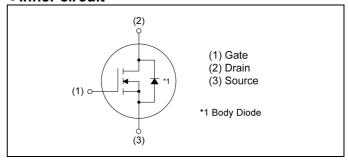
Application

Switching Power Supply

Outline



Inner circuit



Packaging specifications

	Jiiig opcomouncino	
	Packing	Embossed Tape
	Reel size (mm)	330
Туре	Tape width (mm)	24
	Basic ordering unit (pcs)	1000
	Taping code	TL
	Marking	R5016FNJ

● **Absolute maximum ratings** (T_a = 25°C ,unless otherwise specified)

Parameter		Symbol	Value	Unit
Drain - Source voltage		V _{DSS}	500	V
Continuous dusin surrount	T _C = 25°C	I _D *1	±16	А
Continuous drain current	T _C = 100°C	I _D *1	±7.6	А
Pulsed drain current		I _{DP} *2	±64	Α
Gate - Source voltage		V _{GSS}	±30	V
Avalanche current, single pulse		I _{AS} *3	8.0	Α
Avalanche energy, single pulse		E _{AS} *3	17.1	mJ
Avalanche energy, repetitive		E _{AR} *4	3.5	mJ
Power dissipation (T _c = 25°C)		P _D	255	W
Junction temperature		T _j	150	°C
Operating junction and storage ten	nperature range	T _{stg}	-55 to +150	°C
Reverse diode dv/dt		dv/dt	15	V/ns

● Absolute maximum ratings

Parameter	Symbol	Conditions	Values	Unit
Drain - Source voltage slope	dv/dt	$V_{DS} = 400V, I_{D} = 16A$ $T_{j} = 125^{\circ}C$	50	V/ns

●Thermal resistance

Doromotor	Symbol		Values		Unit
Parameter	Symbol	Min.	Тур.	Max.	UTIIL
Thermal resistance, junction - case	R _{thJC}	-	-	0.49	°C/W
Thermal resistance, junction - ambient	R _{thJA}	-	-	80	°C/W
Soldering temperature, wavesoldering for 10s	T _{sold}	-	-	265	°C

• Electrical characteristics $(T_a = 25^{\circ}C)$

Parameter	Cumb al	Conditions		Values		Unit
- Farameter	Symbol	Conditions	Min.	Тур.	Max.	Offic
Drain - Source breakdown voltage	V _{(BR)DSS}	$V_{GS} = 0V$, $I_D = 1mA$	500	-	ı	V
Drain - Source avalanche breakdown voltage	V _{(BR)DS}	$V_{GS} = 0V, I_D = 8A$	-	580	-	V
Zero gate voltage drain current	I _{DSS}	$V_{DS} = 500V, V_{GS} = 0V$ $T_j = 25^{\circ}C$ $T_j = 125^{\circ}C$	-	1 -	100 1000	μΑ
Gate - Source leakage current	I _{GSS}	V _{GS} = ±30V, V _{DS} = 0V	-	-	±100	nA
Gate threshold voltage	V _{GS(th)}	V _{DS} = 10V, I _D = 1mA	3	-	5	V
Static drain - source on - state resistance	R _{DS(on)} *6	$V_{GS} = 10V, I_D = 8.0A$ $T_j = 25^{\circ}C$ $T_j = 125^{\circ}C$	-	0.25 0.53	0.325	Ω
Gate resistance	R_{G}	f = 1MHz, open drain	-	10	-	Ω

● Electrical characteristics (T_a = 25°C)

Davamatav	Cumphal	Conditions		Values		Lloit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Forward Transfer Admittance	Y _{fs} *6	V _{DS} = 10V, I _D = 8.0A	6.2	11	-	S
Input capacitance	C _{iss}	V _{GS} = 0V	-	1700	-	
Output capacitance	C _{oss}	V _{DS} = 25V	-	1000	1	pF
Reverse transfer capacitance	C _{rss}	f = 1MHz	-	35	1	
Effective output capacitance, energy related	C _{o(er)}	V _{GS} = 0V,	-	68.2	-	, L
Effective output capacitance, time related	C _{o(tr)}	V _{DS} = 0V to 400V	-	222	-	pF
Turn - on delay time	t _{d(on)} *6	V _{DD} ≈ 250V, V _{GS} = 10V	-	35	-	
Rise time	t _r *6	I _D = 8.0A	-	60	-	
Turn - off delay time	t _{d(off)} *6	R _L ≃ 31.25Ω	-	110	220	ns
Fall time	t _f *6	$R_G = 10\Omega$	-	35	70	

● Gate charge characteristics (T_a = 25°C)

Darameter	Cymah ol	Conditions		Values		Lloit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Total gate charge	Q_g^{*6}	V _{DD} ≈ 250V	-	46	-	
Gate - Source charge	Q _{gs} *6	I _D = 8A	-	11	-	nC
Gate - Drain charge	Q _{gd} *6	V _{GS} = 10V	-	19	-	
Gate plateau voltage	V _(plateau)	V _{DD} ≈ 250V, I _D = 8A	-	6.3	-	V

^{*1} Limited only by maximum temperature allowed.

^{*2} Pw ≤ 10µs, Duty cycle ≤ 1%

^{*3} L \simeq 500 μ H, V_{DD} = 50V, R_G = 25 Ω , starting T_i = 25°C

^{*4} L \simeq 500 μ H, V_{DD} = 50V, R_G = 25 Ω , starting T_i = 25°C, f = 10kHz

^{*5} Reference measurement circuits Fig.5-1.

^{*6} Pulsed

●Body diode electrical characteristics (Source-Drain) (T_a = 25°C)

Daramatar	Cymah al	Canditions		Values		Lloit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Continuous forward current	I _S *1	T - 25°C	-	-	16	А
Pulse forward current	I _{SP} *2	T _C = 25°C	-	-	64	Α
Forward voltage	V _{SD} *6	V _{GS} = 0V, I _S = 16A	-	-	1.5	V
Reverse recovery time	t _{rr} *6		-	100	-	ns
Reverse recovery charge	Q _{rr} *6	I _S = 16A di/dt = 100A/µs	-	0.3	-	μC
Peak reverse recovery current	I _{rm} *6	- αι/αι – 100/4μ3	-	6.0	-	Α
Peak rate of fall of reverse recovery current	di _{rr} /dt	T _j = 25°C	-	770	-	A/µs

● Typical transient thermal characteristics

Symbol	Value	Unit
R _{th1}	0.0552	
R _{th2}	0.19	K/W
R _{th3}	0.74	

Symbol	Value	Unit
C _{th1}	0.00258	
C _{th2}	0.0113	Ws/K
C _{th3}	0.255	

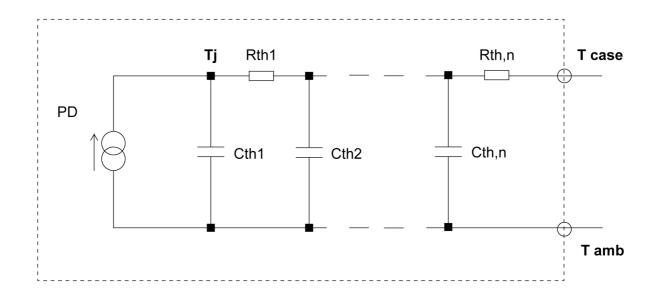


Fig.1 Power Dissipation Derating Curve

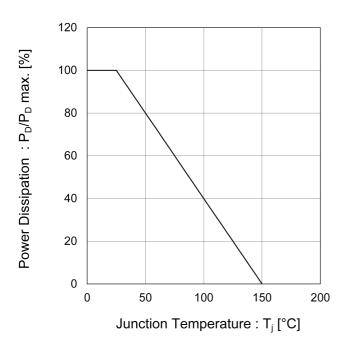


Fig.2 Maximum Safe Operating Area

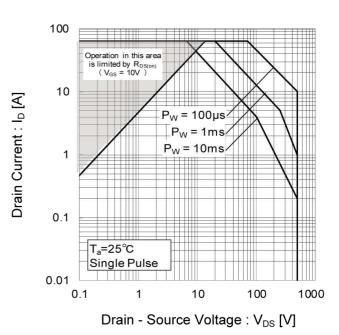


Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

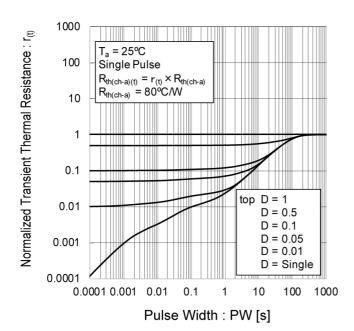


Fig.4 Avalanche Current vs. Inductive Load

10 T_a = 25°C 9 $V_{DD} = 50V$, $R_{G} = 25\Omega$ $V_{GF} = 10V$, $V_{GR} = 0V$ Avalanche Current : IAR [A] 8 7 6 5 4 3 2 1 0 10 0.01 Coil Inductance : L [mH]

Fig.5 Avalanche Power Losses

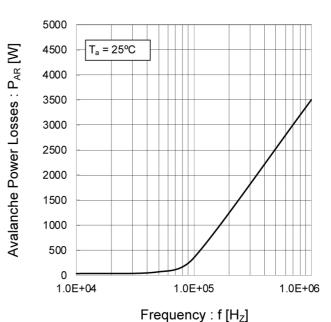


Fig.6 Avalanche Energy Derating Curve vs. Junction Temperature

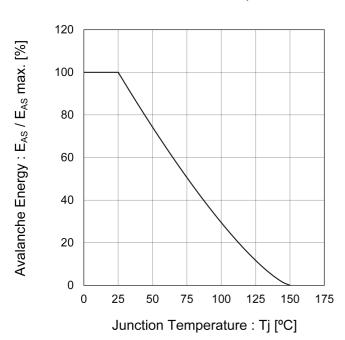
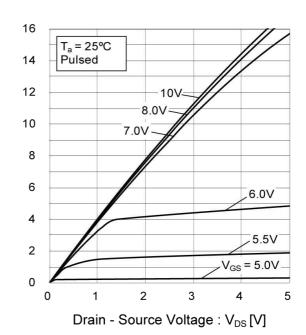


Fig.7 Typical Output Characteristics(I)

16 T_a = 25°C Pulsed 14 8.0V 7.0V 12 Drain Current : I_D [A] 10 8 6 4 2 0 0 20 30 50 10 40 Drain - Source Voltage: V_{DS} [V]

Fig.8 Typical Output Characteristics(II)



Drain Current : I_D [A]

Fig.9 Tj = 150°C Typical Output Characteristics (I)

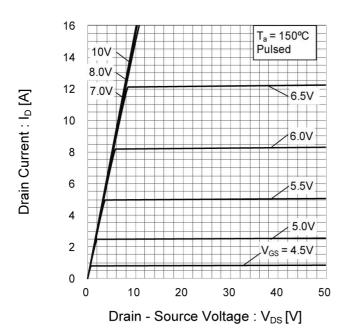
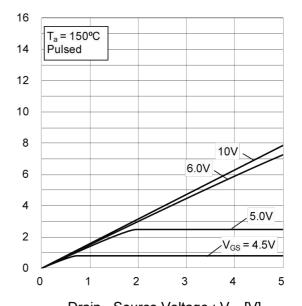


Fig.10 Tj = 150°C Typical Output Characteristics (II)



Drain - Source Voltage : V_{DS} [V]

Drain Current : I_D [A]

Fig.11 Breakdown Voltage vs. Junction Temperature

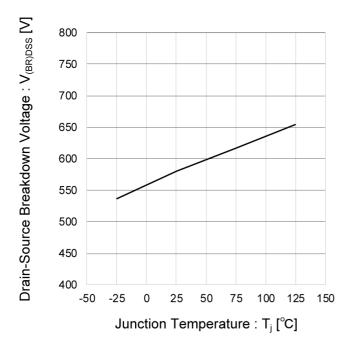


Fig.12 Typical Transfer Characteristics

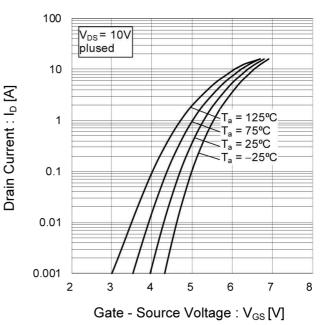


Fig.13 Gate Threshold Voltage vs. Junction Temperature

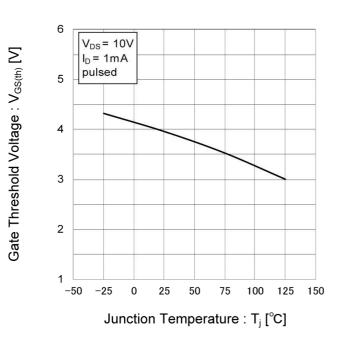


Fig.14 Transconductance vs. Drain Current

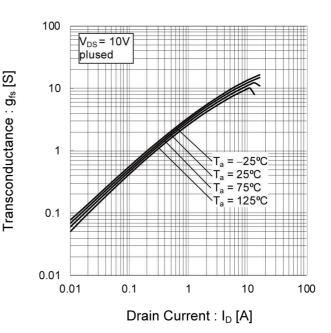


Fig.15 Static Drain - Source On - State Resistance vs. Gate Source Voltage

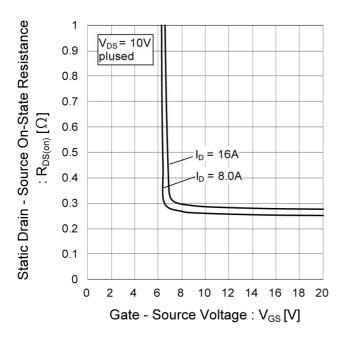


Fig.16 Static Drain - Source On - State Resistance vs. Junction Temperature

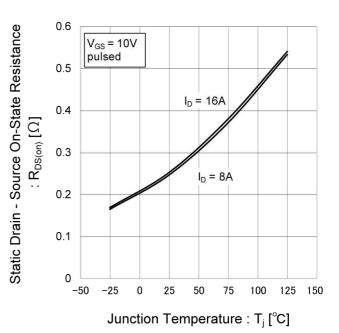


Fig.17 Static Drain - Source On - State Resistance vs. Drain Current

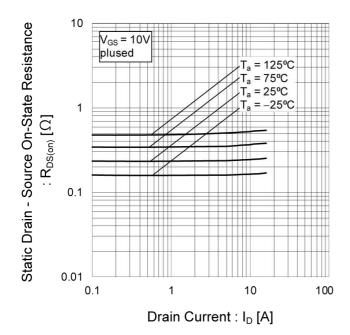
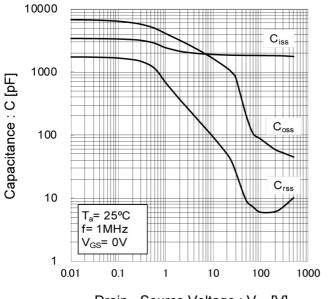
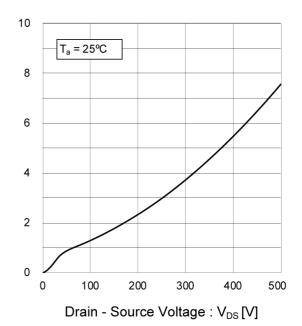


Fig.18 Typical Capacitance vs. Drain -Source Voltage



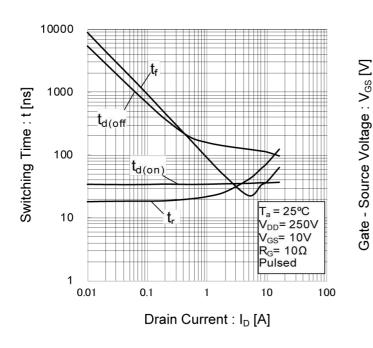
Coss Stored Energy : $E_{\rm oss}$ [μ J]

Fig.19 Coss Stored Energy



Drain - Source Voltage: V_{DS}[V]

Fig.20 Switching Characteristics

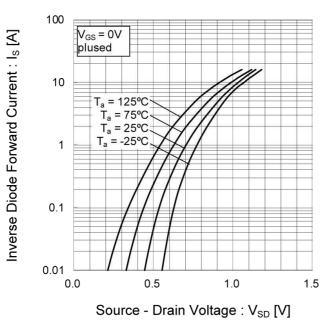


15 T_a= 25℃ V_{DD}= 250V

I_D= 16A Pulsed 10 5 0 10 20 30 0 40 50 60 70 Total Gate Charge: Qq [nC]

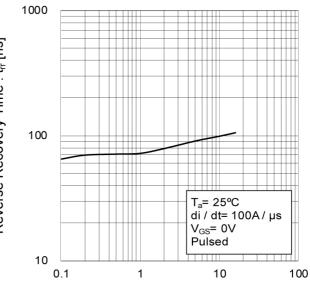
Fig.21 Dynamic Input Characteristics

Fig.22 Inverse Diode Forward Current vs. Source - Drain Voltage



Reverse Recovery Time : \mathfrak{t}_{rr} [ns]

Fig.23 Reverse Recovery Time vs.
Inverse Diode Forward Current



Inverse Diode Forward Current: I_S [A]

Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

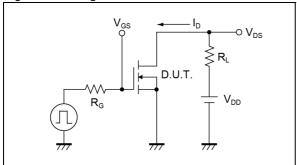


Fig.2-1 Gate Charge Measurement Circuit

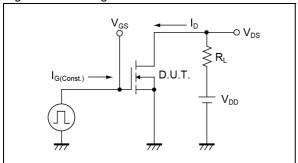


Fig.3-1 Avalanche Measurement Circuit

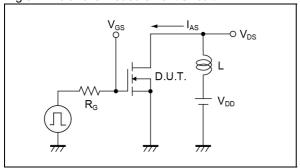


Fig.4-1 dv/dt Measurement Circuit

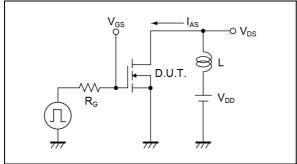


Fig.5-1 di/dt Measurement Circuit

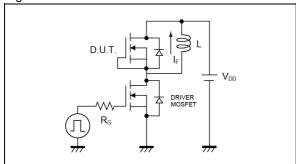


Fig.1-2 Switching Waveforms

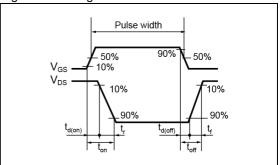


Fig.2-2 Gate Charge Waveform

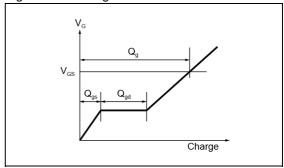


Fig.3-2 Avalanche Waveform

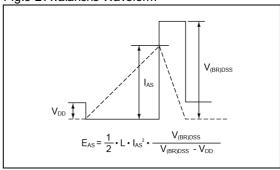


Fig.4-2 dv/dt Waveform

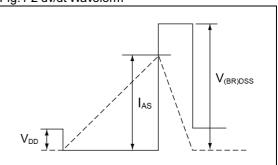
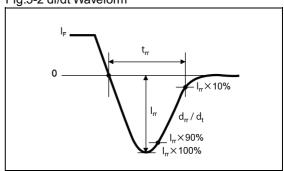
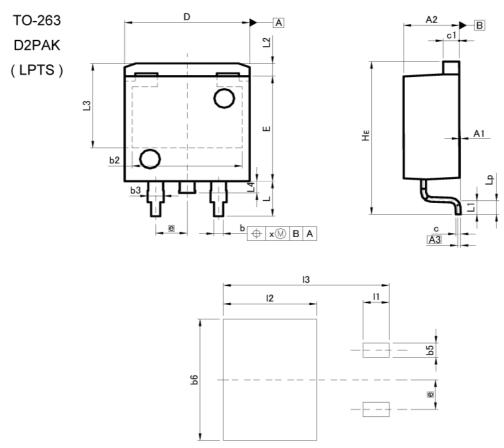


Fig.5-2 di/dt Waveform



Dimensions



Pattern of terminal position areas [Not a pattern of soldering pads]

DIM	MILIM	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
A1	0.00	0.30	0.000	0.012
A2	4.30	4.70	0.169	0.185
A3	0.	25	0.0	10
b	0.68	0.98	0.027	0.039
b2	8.	90	0.3	50
b3	1.14	1.44	0.045	0.057
С	0.30	0.60	0.012	0.024
c1	1.10	1.50	0.043	0.059
D	9.80	10.40	0.386	0,409
E	8.80	9.20	0.346	0.362
е	2.	54	0.100	
HE	12.80	13.40	0.504	0.528
L	2.70	3.30	0.106	0.130
L1	1.	20	0.0	147
L2	1.	10	0.0	143
L3	7.	25	0.285	
L4	1.	00	0.0	39
Lp	0.90	1.50	0.035	0.059
Х	=:	0.25	177	0.010
T	MILIM	FTFRS	INC	HES
DIM ⊢	A ATA I	MAN	A 4Th I	BAAV

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b5	-	1.23	100	0.049
b6	4:	10.40	-	0.409
	살기	2.10	. 2	0.083
12	55 6	7.55	177	0.297
13	=	13.40	-	0.528

Dimension in mm/inches



Rev.003

Notice

Precaution on using ROHM Products

1. Our Products are designed and manufactured for application in ordinary electronic equipments (such as AV equipment, OA equipment, telecommunication equipment, home electronic appliances, amusement equipment, etc.). If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment (Note 1), transport equipment, traffic equipment, aircraft/spacecraft, nuclear power controllers, fuel controllers, car equipment including car accessories, safety devices, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

(Note1) Medical Equipment Classification of the Specific Applications

JAPAN	USA	EU	CHINA
CLASSⅢ	CL ACCTI	CLASS II b	CLASSIII
CLASSIV	CLASSII	CLASSⅢ	

- 2. ROHM designs and manufactures its Products subject to strict quality control system. However, semiconductor products can fail or malfunction at a certain rate. Please be sure to implement, at your own responsibilities, adequate safety measures including but not limited to fail-safe design against the physical injury, damage to any property, which a failure or malfunction of our Products may cause. The following are examples of safety measures:
 - [a] Installation of protection circuits or other protective devices to improve system safety
 - [b] Installation of redundant circuits to reduce the impact of single or multiple circuit failure
- 3. Our Products are designed and manufactured for use under standard conditions and not under any special or extraordinary environments or conditions, as exemplified below. Accordingly, ROHM shall not be in any way responsible or liable for any damages, expenses or losses arising from the use of any ROHM's Products under any special or extraordinary environments or conditions. If you intend to use our Products under any special or extraordinary environments or conditions (as exemplified below), your independent verification and confirmation of product performance, reliability, etc, prior to use, must be necessary:
 - [a] Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
 - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
 - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

Precautions Regarding Application Examples and External Circuits

- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
- You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

Precaution for Electrostatic

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

Precaution for Storage / Transportation

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
 - [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- Even under ROHM recommended storage condition, solderability of products out of recommended storage time period
 may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is
 exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

Precaution for Product Label

A two-dimensional barcode printed on ROHM Products label is for ROHM's internal use only.

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When disposing Products please dispose them properly using an authorized industry waste company.

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